Very Low Supply Current 3-Pin Microprocessor Reset Monitor

The MAX803/NCP803 is a cost–effective system supervisor circuit designed to monitor $V_{\rm CC}$ in digital systems and provide a reset signal to the host processor when necessary. No external components are required.

The reset output is driven active within 10 µsec of V_{CC} falling through the reset voltage threshold. Reset is maintained active for a timeout period which is trimmed by the factory after V_{CC} rises above the reset threshold. The MAX803/NCP803 has an open drain active—low \overline{RESET} output. Both devices are available in SOT—23 and SC—70 packages.

The MAX803/NCP803 is optimized to reject fast transient glitches on the V_{CC} line. Low supply current of 0.5 μA (V_{CC} = 3.2 V) make these devices suitable for battery powered applications.

Features

- Precision V_{CC} Monitor for 1.5 V, 2.5 V, 3.0 V, 3.3 V, and 5.0 V Supplies
- Precision Monitoring Voltages from 1.2 V to 4.9 V Available in 100 mV Steps
- Four Guaranteed Minimum Power–On Reset Pulse Width Available (1 ms, 20 ms, 100 ms, and 140 ms)
- RESET Output Guaranteed to $V_{CC} = 1.0 \text{ V}$
- Low Supply Current
- V_{CC} Transient Immunity
- No External Components
- Wide Operating Temperature: -40°C to 105°C
- These Devices are Pb-Free and are RoHS Compliant

Typical Applications

- Computers
- Embedded Systems
- Battery Powered Equipment
- Critical Microprocessor Power Supply Monitoring

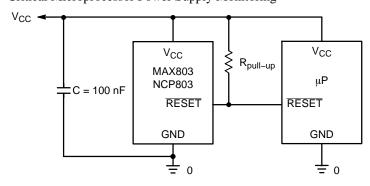


Figure 1. Typical Application Diagram



ON Semiconductor®

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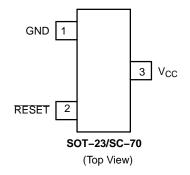
xxx = Specific Device Code

M = Date Code

= Pb–Free Package

(Note: Microdot may be in either location)

PIN CONFIGURATION



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 8 of this data sheet.

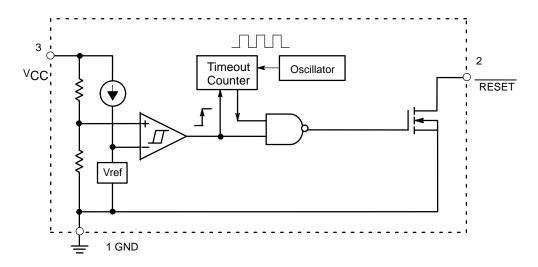


Figure 2. NCP803, MAX803 Series Open-Drain Active-Low Output

PIN DESCRIPTION

Pin No.	Symbol	Description
1	GND	Ground
2	RESET	RESET output remains low while V_{CC} is below the reset voltage threshold, and for a reset timeout period after V_{CC} rises above reset threshold.
3	V _{CC}	Supply Voltage: $C = 100 \text{ nF}$ is recommended as a bypass capacitor between V_{CC} and GND.

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage (V _{CC} to GND)	V _{CC}	-0.3 to 6.0	V
RESET Output Voltage (CMOS)		-0.3 to (V _{CC} + 0.3)	V
Input Current, V _{CC}		20	mA
Output Current, RESET		20	mA
dV/dt (V _{CC})		100	V/μsec
Thermal Resistance, Junction–to–Air (Note 1) SOT–23 SC–70	00/	301 314	°C/W
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C
Lead Temperature (Soldering, 10 Seconds)	T _{sol}	+260	°C
ESD Protection Human Body Model (HBM): Following Specification JESD22-A114 Machine Model (MM): Following Specification JESD22-A115		2000 200	V
Latchup Current Maximum Rating: Following Specification JESD78 Class II Positive Negative		200 200	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. This based on a 35x35x1.6mm FR4 PCB with 10mm² of 1 oz copper traces under natural convention conditions and a single component

2. The maximum package power dissipation limit must not be exceeded.

$$P_D = \frac{T_J(max) - T_A}{R_{0.1A}}$$
 with $T_{J(max)} = 150^{\circ}C$

characterization.

ELECTRICAL CHARACTERISTICS $T_A = -40^{\circ}C$ to $+105^{\circ}C$ unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$. (Note 3)

Characteristic	Symbol	Min	Тур	Max	Unit
V_{CC} Range $T_{\Delta} = 0^{\circ}C$ to +70°C		1.0		<i></i>	V
$T_A = 0^{\circ}C \text{ to } +70^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +105^{\circ}C \text{ (Note 4)}$		1.0 1.2	_	5.5 5.5	
Supply Current	Icc				μΑ
V _{CC} = 3.3 V	.00				μ
$T_A = -40^{\circ}C$ to $+85^{\circ}C$		_	0.5	1.2	
$T_A = 85^{\circ}C \text{ to } +105^{\circ}C \text{ (Note 5)}$		-	_	2.0	
$V_{CC} = 5.5 \text{ V}$			0.0	4.0	
$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $T_A = 85^{\circ}\text{C to } +105^{\circ}\text{C (Note 5)}$		_	0.8	1.8 2.5	
Reset Threshold (V _{in} Decreasing) (Note 6)	V _{TH}	-	_	2.5	V
MAX803SQ463/NCP803SN463	VIH				v
$T_A = +25^{\circ}C$		4.56	4.63	4.70	
$T_A = -40$ °C to +85°C		4.51	_	4.75	
$T_A = +85^{\circ}C \text{ to } +105^{\circ}C \text{ (Note 5)}$		4.40	_	4.88	
MAX803SQ438/NCP803SN438					7
$T_A = +25^{\circ}C$		4.31	4.38	4.45	
$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$		4.27		4.49	
$T_A = +85^{\circ}C \text{ to } +105^{\circ}C \text{ (Note 5)}$		4.16		4.60	
NCP803SN400		2.04	4.00	4.06	
$T_A = +25^{\circ}C$ $T_A = -40^{\circ}C$ to +85°C		3.94 3.90	4.00	4.06 4.10	
$T_A = +85^{\circ}\text{C to } +105^{\circ}\text{C (Note 5)}$		3.80		4.10	
MAX803SQ308/NCP803SN308		0.00		0	-
T _A = +25°C		3.04	3.08	3.11	
$T_A = -40$ °C to +85°C		3.00	_	3.15	
$T_A = +85^{\circ}C \text{ to } +105^{\circ}C \text{ (Note 5)}$		2.92	_	3.23	
MAX803SQ293/NCP803SN293					7
$T_A = +25^{\circ}C$		2.89	2.93	2.96	
$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$		2.85	_	3.00	
$T_A = +85^{\circ}C \text{ to } +105^{\circ}C \text{ (Note 5)}$		2.78	_	3.08	4
NCP803SN263		2.50	2.62	2.66	
$T_A = +25^{\circ}C$ $T_A = -40^{\circ}C$ to +85°C		2.59 2.55	2.63	2.66 2.70	
$T_A = +85$ °C to +105°C (Note 5)		2.50	_	2.76	
NCP803SN232				•	+
$T_A = +25^{\circ}C$		2.29	2.32	2.35	
$T_A = -40$ °C to +85°C		2.26	_	2.38	
$T_A = +85^{\circ}C$ to $+105^{\circ}C$ (Note 5)		2.20	_	2.45	
NCP803SN160					
$T_A = +25^{\circ}C$		1.58	1.60	1.62	
$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$		1.56	_	1.64	
T _A = +85°C to +105°C (Note 5) MAX803SN120, MAX803SQ120		1.52	_	1.68	4
$T_A = +25^{\circ}C$		1.18	1.20	1.22	
$T_{\Delta} = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$		1.17	-	1.23	
T_A° = +85°C to +105°C (Note 5)		1.14	-	1.26	<u> </u>
Detector Voltage Threshold Temperature Coefficient		ı	30	_	ppm/°C
CC to Reset Delay V _{CC} = V _{TH} to (V _{TH} – 100 mV)		-	10	-	μsec
Reset Active TimeOut Period (Note 6)	t _{RP}	4.0		0.0	msec
MAX803SN(Q)293D1 MAX803SN(Q)293D2/MAX803SN(Q)308D2		1.0 20	_	3.3 66	
MAX803SN(Q)293D3		100	_	330	
MAX803SN(Q)293		140	-	460	
RESET Output Voltage Low	V _{OL}	_	-	0.3	V
$V_{CC} = V_{TH} - 0.2 V$					
$1.6 \text{ V} \le \text{V}_{TH} \le 2.0 \text{ V}, \text{I}_{SINK} = 0.5 \text{ mA}$					
$2.1 \text{ V} \le \text{V}_{TH} \le 4.0 \text{ V}, \text{I}_{SINK} = 1.2 \text{ mA}$					
$4.1 \text{ V} \le \text{V}_{TH} \le 4.9 \text{ V}, \text{I}_{SINK} = 3.2 \text{ mA}$					
RESET Leakage Current $V_{CC} > V_{TH}$, RESET De-asserted	I _{LEAK}	-	_	1	μΑ

Production testing done at T_A = 25°C, over temperature limits guaranteed by design.
 For NCV automotive devices, this temperature range is T_A = -40°C to +125°C.
 For NCV automotive devices, this temperature range is T_A = +85°C to +125°C.
 Contact your ON Semiconductor sales representative for other threshold voltage and timeout options.

TYPICAL OPERATING CHARACTERISTICS

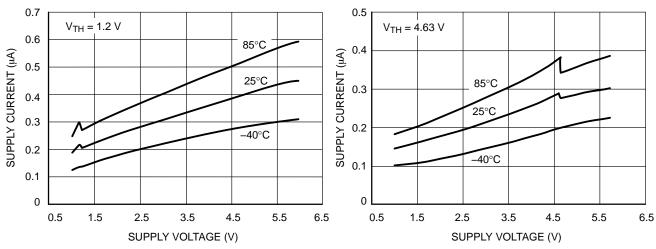


Figure 3. Supply Current vs. Supply Voltage

Figure 4. Supply Current vs. Supply Voltage

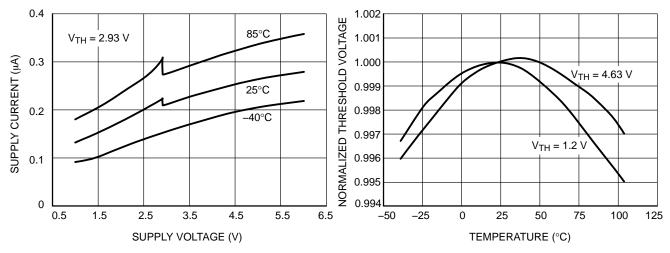


Figure 5. Supply Current vs. Supply Voltage

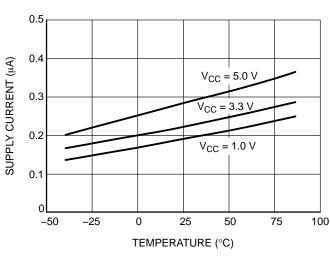


Figure 7. Supply Current vs. Temperature

Figure 6. Normalized Reset Threshold Voltage vs. Temperature

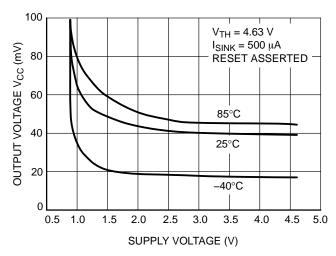


Figure 8. Output Voltage Low vs. Supply Voltage

TYPICAL OPERATING CHARACTERISTICS

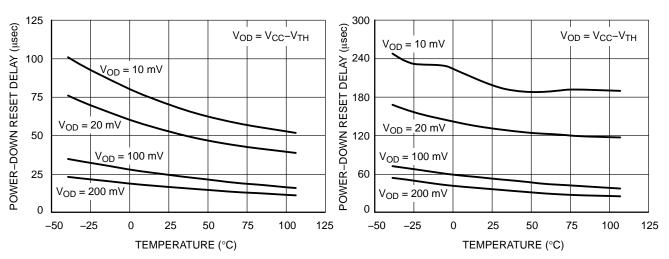


Figure 9. Power–Down Reset Delay vs. Temperature and Overdrive (V_{TH} = 1.2 V)

Figure 10. Power–Down Reset Delay vs. Temperature and Overdrive (V_{TH} = 4.63 V)

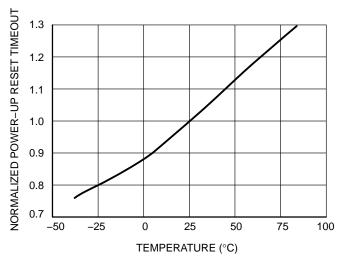


Figure 11. Normalized Power–Up Reset vs. Temperature

Detail Operation Description

The MAX803, NCP803 series microprocessor reset supervisory circuits are designed to monitor the power supplies in digital systems and provide a reset signal to the processor without any external components. Figure 2 shows the timing diagram and a typical application below. Initially consider that input voltage V_{CC} is at a nominal level greater than the voltage detector upper threshold (v_{TH}). And the

RESET (RESET) output voltage (Pin 2) will be in the high state for MAX803 and NCP803 devices. If there is an input

power interruption and V_{CC} becomes significantly deficient, it will fall below the lower detector threshold (V_{TH-}). This event causes the RESET output to be in the low state for the MAX803 and NCP803 devices. After completion of the power interruption, V_{CC} will rise to its nominal level and become greater than the V_{TH} . This sequence activates the internal oscillator circuitry and digital counter to count. After the count of the timeout period, the reset output will revert back to the original state.

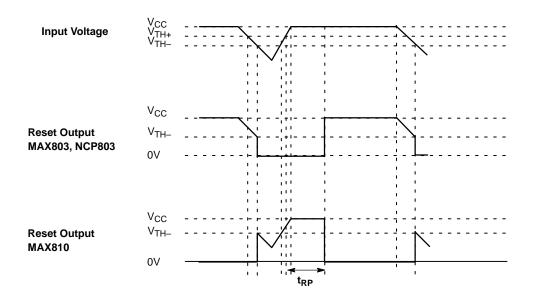
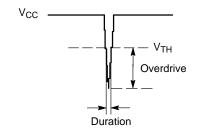


Figure 12. Timing Waveforms

APPLICATIONS INFORMATION

V_{CC} Transient Rejection

The MAX803/NCP803 series provides accurate V_{CC} monitoring and reset timing during power—up, power—down, and brownout/sag conditions, and rejects negative—going transients (glitches) on the power supply line. Figure 13 shows the maximum transient duration vs. maximum negative excursion (overdrive) for glitch rejection. Any combination of duration and overdrive which lies under the curve will not generate a reset signal. Combinations above the curve are detected as a brownout or power—down. Typically, transient that goes 100 mV below the reset threshold and lasts 5.0 μ s or less will not cause a reset pulse. Transient immunity can be improved by adding a capacitor in close proximity to the V_{CC} pin of the MAX803.



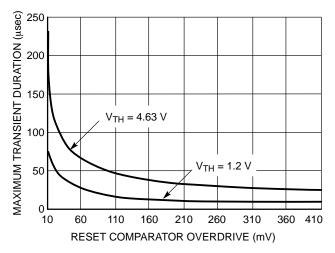
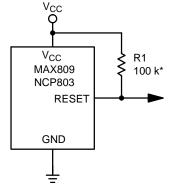


Figure 13. Maximum Transient Duration vs. Overdrive for Glitch Rejection at 25°C

RESET Signal Integrity During Power–Down

The MAX803/NCP803 \overline{RESET} output is valid to $V_{CC}=1.0$ V. Below this voltage the output becomes an "open circuit" and does not sink current. This means CMOS logic inputs to the Microprocessor will be floating at an undetermined voltage. Most digital systems are completely shutdown well above this voltage. However, in situations where \overline{RESET} must be maintained valid to $V_{CC}=0$ V, since

the NCP803/MAX803 has Open–Drain and active–low output, it typically uses a pullup resistor. With this device, RESET will most likely not maintain an active condition, but will drift to a non–active level due to the pullup resistor and the reduced sinking capability of the open–drain device. Therefore, this device is not recommended for applications where the $\overline{\text{RESET}}$ pin is required to be valid down to $V_{CC} = 0 \text{ V}$.



*Assume High-Z Reset Input to Microprocessor

Figure 14. RESET Signal Integrity

MAX803 RESET Output Allows Use With Two Power Supplies

In numerous applications the pullup resistor place on the \overline{RESET} output is connected to the supply voltage monitored by the IC. Nevertheless, a different supply voltage can also power this output and so level—shift from the monitored supply to reset the microprocessor. However, if the NCP803/MAX803's supply goes blew 1 V, the \overline{RESET} output ability to sink current will decrease and the result is a high state on the pin even though the supply's IC is under the threshold level. This occurs at a V_{CC} level that depends on the R_{pullup} value and the voltage which is connected.

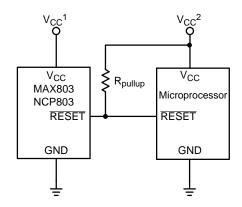


Figure 15. MAX803 RESET Output with Two Supplies

ORDERING, MARKING AND THRESHOLD INFORMATION

Part Number	Vth** (V)	Time out*** (ms)	Description	Marking	Package	Shipping [†]
NCP803SN160T1G	1.60	140–460		SCQ	SOT23-3 (Pb-Free)	
NCP803SN232T1G	2.32	140–460		SQR	SOT23-3 (Pb-Free)	
NCP803SN263T1G	2.63	140–460		SQC	SOT23-3 (Pb-Free)	
NCP803SN293T1G	2.93	140–460		SQD	SOT23-3 (Pb-Free)	
NCP803SN308T1G	3.08	140–460		SQE	SOT23-3 (Pb-Free)	
NCP803SN400T1G	4.00	140–460		RAD	SOT23-3 (Pb-Free)	
NCP803SN438T1G	4.38	140–460		SQF	SOT23-3 (Pb-Free)	
NCP803SN463T1G	4.63	140–460		SQG	SOT23-3 (Pb-Free)	
NCP803SN120T1G	1.20	140–460	Open Drain RESET	SSW	SOT23-3 (Pb-Free)	
NCP803SN293D1T1G	2.93	1–3.3		SSX	SOT23-3 (Pb-Free)	
NCP803SN293D2T1G	2.93	20–66		SSY	SOT23-3 (Pb-Free)	
NCP803SN293D3T1G	2.93	100–330		SSZ	SOT23-3 (Pb-Free)	3000 / Tape & Reel
MAX803SQ120T1G	1.20	140–460		ZV	SC70-3 (Pb-Free)	
MAX803SQ263T1G	2.63	140–460		SX	SC70-3 (Pb-Free)	
MAX803SQ293T1G	2.93	140–460		ZW	SC70-3 (Pb-Free)	
MAX803SQ308T1G	3.08	140–460		ZX	SC70-3	
NCV803SQ308T1G*		140–460		ZA	(Pb-Free)	
MAX803SQ438T1G	4.38	140–460		ZY	SC70-3 (Pb-Free)	
MAX803SQ463T1G	4.63	140–460		ZZ	SC70-3 (Pb-Free)	
MAX803SQ293D1T1G	2.93	1–3.3		YA	SC70-3 (Pb-Free)	
MAX803SQ293D2T1G	2.93	20–66		YB	SC70-3 (Pb-Free)	
MAX803SQ308D2T1G	3.08	20–66		SY	SC70-3	
NCV803SQ308D2T1G*		20–66		CY	(Pb-Free)	
MAX803SQ293D3T1G	2.93	100–330		YC	SC70-3 (Pb-Free)	
NCP803SN293T3G	2.93	140–460		SQD	SOT23-3 (Pb-Free)	10000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

**Contact your ON Semiconductor sales representative for other threshold voltage options.

^{***}Contact your ON Semiconductor sales representative for timeout options availability for other threshold voltage options.

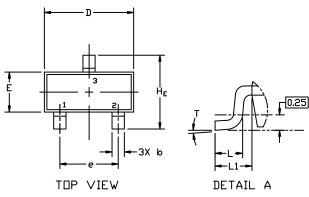




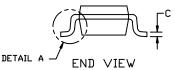
SOT-23 (TO-236) **CASE 318 ISSUE AT**

DATE 01 MAR 2023









NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIM	IETERS			INCHES	
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
A	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
U	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
T	0*		10*	0*		10°



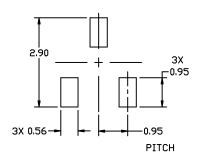


XXX = Specific Device Code

= Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

STYLES ON PAGE 2

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DESCRIPTION:	SOT-23 (TO-236)		PAGE 1 OF 2		

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



SOT-23 (TO-236) CASE 318 ISSUE AT

DATE 01 MAR 2023

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	ı	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE		PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE		2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE		3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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SC-70 (SOT-323) **CASE 419** ISSUE R

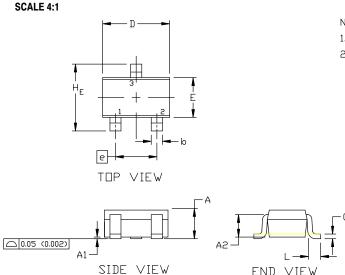
END VIEW

DATE 11 OCT 2022

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH

	M:	MILLIMETERS			INCHES	
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2		0.70 REF			0.028 BS	C
b	0.30	0.35	0.40	0.012	0.014	0.016
С	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.00	2.20	0.071	0.080	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC				0.026 BS	C
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095



GENERIC MARKING DIAGRAM

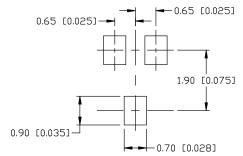


= Specific Device Code XX

Μ = Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.



For additional information on our Pb-Free strategy and soldering details, please download the ID Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

SOLDERING FOOTPRINT

STYLE 1: CANCELLED	STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE	STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. CATHODE	
STYLE 6: PIN 1. EMITTER	STYLE 7: PIN 1. BASE	STYLE 8: PIN 1. GATE	STYLE 9: PIN 1. ANODE	STYLE 10: PIN 1. CATHODE	STYLE 11: PIN 1. CATHODE
2. BASE	2. EMITTER	2. SOURCE	2. CATHODE	2. ANODE	2. CATHODE
COLLECTOR	COLLECTOR	3. DRAIN	CATHODE-ANODE	3. ANODE-CATHODE	CATHODE

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